Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic and metal
Overall Length:
0.097 inches
Overall Diameter:
0.124 inches
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, dc
Current Rating Per Characteristic:
10.00 microamperes all primaries horsepower metric
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0